



SRA2205M

PNP Silicon Transistor

Descriptions

- Switching application
- Interface circuit and driver circuit application

Features

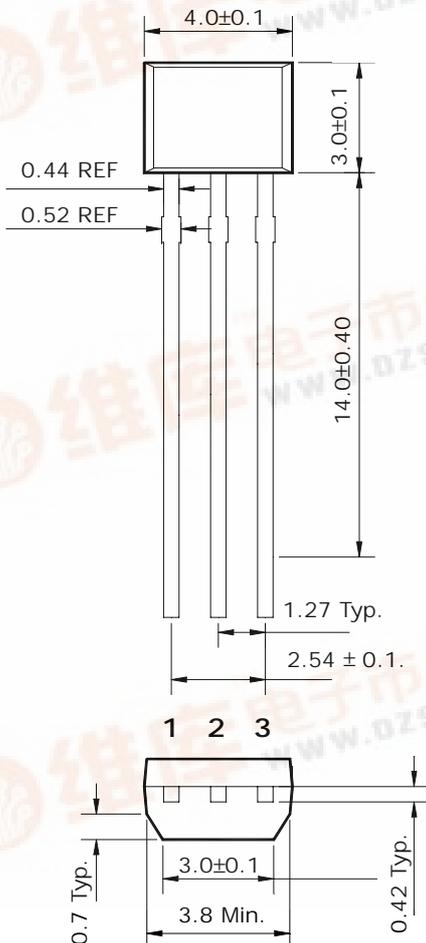
- With built-in bias resistors
- Simplify circuit design
- Reduce a quantity of parts and manufacturing process
- High packing density

Ordering Information

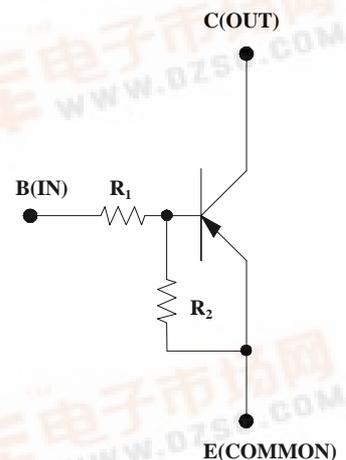
Type NO.	Marking	Package Code
SRA2205M	2205	TO-92M

Outline Dimensions

unit : mm



• Equivalent Circuit



R ₁	R ₂
2.2KΩ	47KΩ

PIN Connections

1. Emitter
2. Collector
3. Base



Absolute maximum ratings**(Ta=25°C)**

Characteristic	Symbol	Ratings	Unit
Out Voltage	V_O	-50	V
Input Voltage	V_I	-12	V
Out Current	I_O	-100	mA
Power Dissipation	P_D	400	mW
Junction Temperature	T_J	150	°C
Storage Temperature	T_{STG}	-55 ~ 150	°C

Electrical Characteristics**(Ta=25°C)**

Characteristic	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Output Cut-off Current	$I_{O(OFF)}$	$V_O = -50V, V_I = 0$	-	-	-500	nA
DC Current Gain	G_I	$V_O = -5V, I_O = -10mA$	80	200	-	-
Output Voltage	$V_{O(ON)}$	$I_O = -10mA, I_I = -0.5mA$	-	-0.1	-0.3	V
Input Voltage (ON)	$V_{I(ON)}$	$V_O = -0.2V, I_O = -5mA$	-	-	-1.1	V
Input Voltage (OFF)	$V_{I(OFF)}$	$V_O = -5V, I_O = -0.1mA$	-0.4	-	-	V
Transition Frequency	f_T^*	$V_O = -10V, I_O = -5mA$	-	200	-	MHz
Input Current	I_I	$V_I = -5V$	-	-	-3.6	mA

* : Characteristic of Transistor Only

Electrical Characteristic Curves

Fig. 1 $I_o - V_{I(ON)}$

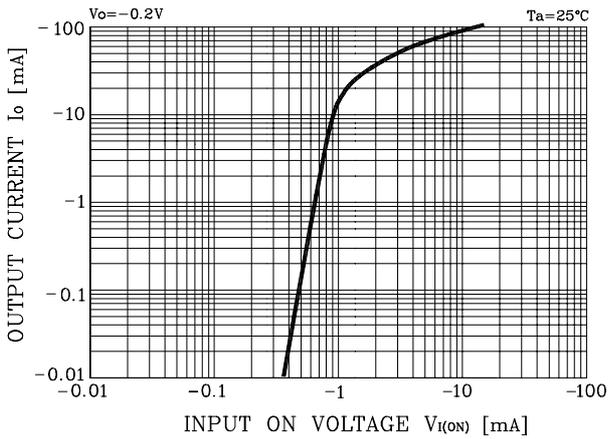


Fig. 2 $I_o - V_{I(OFF)}$

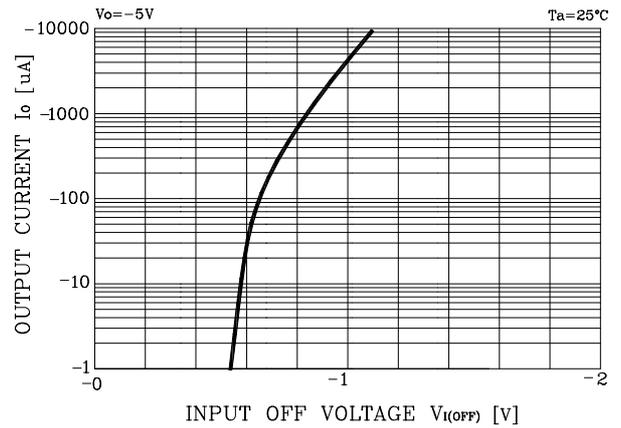


Fig. 3 $G_I - I_o$

